

# **Description**

The AO4443 uses advanced trench technology

to provide excellent R<sub>DS(ON)</sub>, low gate charge and

operation with gate voltages as low as 2.5V. This

device is suitable for use as a

Battery protection or in other Switching application.



SOP-8 (SOIC-8)

**General Features** 

 $V_{DS} = -40 V I_{D} = -13 A$ 

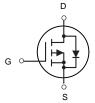
 $R_{DS(ON)}$  < 19m $\Omega$  @  $V_{GS}$ =10V

# **Application**

Battery protection

Load switch

Uninterruptible power supply



P-Channel MOSFET

# **Package Marking and Ordering Information**

Product ID	Pack	Brand	Qty(PCS)
AO4443	SOP-8(SOIC-8)	HXY MOSFET	3000

## Absolute Maximum Ratings (Tc=25°C unless otherwise noted)

Symbol	Parameter	Rating	Units
V <sub>DS</sub>	Drain-Source Voltage	- 40	V
VGS	Gate-Source Voltage	±20	V
I <sub>D</sub> @T <sub>A</sub> =25°C	Drain Current <sup>3</sup> , V <sub>GS</sub> @ 10V	-13	А
IDM	Pulsed Drain Current <sup>1</sup>	-52	Α
P <sub>D</sub> @T <sub>A</sub> =25°C	Total Power Dissipation	3	W
TSTG	Storage Temperature Range	-55 to 150	°C
TJ	Operating Junction Temperature Range	-55 to 150	°C
Rthj-a	Maximum Thermal Resistance, Junction-ambient <sup>3</sup>	41	°C/W



# Electrical Characteristics (T<sub>J</sub> = 25°C, unless otherwise noted)

Parameter		Symbol	Test Conditions	Min.	Тур.	Max.	Unit
Static Characteristics			,		l	l	
Drain-Source Breakdown Voltage		V <sub>(BR)DSS</sub>	V <sub>GS</sub> = 0V, I <sub>D</sub> = -250μA	-40	-	-	V
Gate-body Leakage current		Igss	V <sub>DS</sub> = 0V, V <sub>GS</sub> = ±20V		-	±100	nA
Zero Gate Voltage Drain Current	TJ=25°C		V <sub>DS</sub> = -40V, V <sub>GS</sub> = 0V	-	-	-1	μA
	T <sub>J</sub> =100°C	IDSS		-	-	-100	
Gate-Threshold Voltage		V <sub>GS(th)</sub>	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$	-1.0	-1.5	-2.2	V
<u> </u>		_	V <sub>GS</sub> = -10V, I <sub>D</sub> = -10A	-	14.0	19	mΩ
Drain-Source On-Resistance <sup>4</sup>		R <sub>DS(on)</sub>	V <sub>GS</sub> = -4.5V, I <sub>D</sub> = -5 A	- 19.5 29		25	
Forward Transconductance <sup>4</sup>		<b>g</b> fs	V <sub>DS</sub> = -10V, I <sub>D</sub> = -10A	-	44	-	S
Dynamic Characteristics5	1	•	,				
Input Capacitance		C <sub>iss</sub>		-	2525	_	
Output Capacitance		Coss	$V_{DS} = -20V, V_{GS} = 0V,$ f = 1MHz	-	190	-	pF
Reverse Transfer Capacitance		C <sub>rss</sub>		-	172	-	
Gate Resistance		Rg	f=1MHz	-	10	-	Ω
Switching Characteristics	5	<u> </u>	,				
Total Gate Charge		Qg		-	35	-	nC
Gate-Source Charge		Qgs	$V_{GS} = -10V, V_{DS} = -20V,$ $I_{D} = -10A$	-	5.5	-	
Gate-Drain Charge		Q <sub>gd</sub>		-	8	-	
Turn-On Delay Time		t <sub>d(on)</sub>		-	14.5	-	. ns
Rise Time		tr	$V_{GS} = -10V, V_{DD} = -20V,$	-	20.2	-	
Turn-Off Delay Time		t <sub>d(off)</sub>	$R_G = 3\Omega$ , $I_D = -10A$	-	32	-	
Fall Time		tf		-	10	-	
Drain-Source Body Diode	Character	istics	I	I	ı	ı	<u> </u>
Diode Forward Voltage <sup>4</sup>		V <sub>SD</sub>	Is = -10A, V <sub>GS</sub> = 0V	-	_	-1.2	V
Continuous Source Current	T <sub>C</sub> =25°C	Is	-	-	_	-13	Α

### Note:

- 1. Repetitive rating, pulse width limited by junction temperature  $T_{J(MAX)}$ =150°C.
- 2. The EAS data shows Max. rating . The test condition is  $V_{DD}$ = -25V,  $V_{GS}$ = -10V, L= 0.1mH,  $I_{AS}$ = -34A.
- 3. The data tested by surface mounted on a 1 inch2 FR-4 board with 2OZ copper, The value in any given application depends on the user's specific board design.
- 4. The data tested by pulsed , pulse width  $\leq$  300us , duty cycle  $\leq$  2%.
- 5. This value is guaranteed by design hence it is not included in the production test.



# **Typical Characteristics**

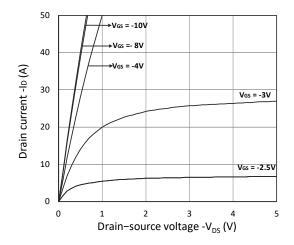


Figure 1. Output Characteristics

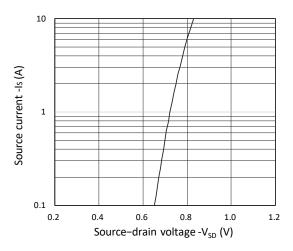


Figure 3. Forward Characteristics of Reverse

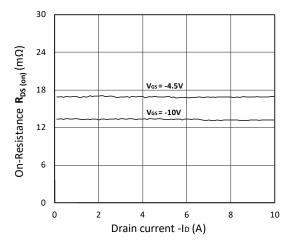


Figure 5.  $R_{DS(ON)}$  vs.  $I_D$ 

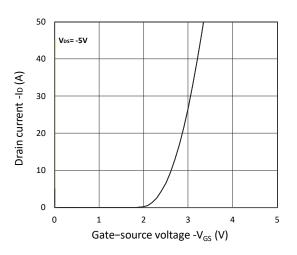


Figure 2. Transfer Characteristics

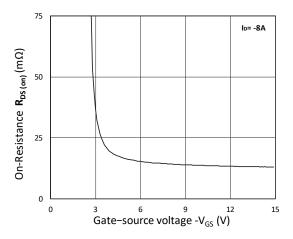


Figure 4.  $R_{DS(ON)}$  vs.  $V_{GS}$ 

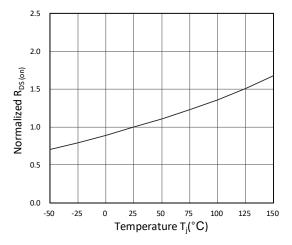


Figure 6. Normalized  $R_{DS(on)}$  vs. Temperature

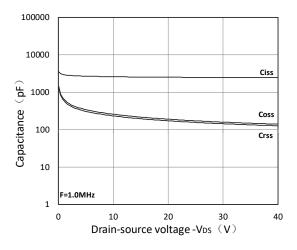


Figure 7. Capacitance Characteristics

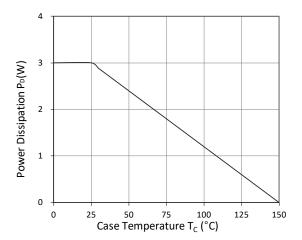


Figure 9. Power Dissipation

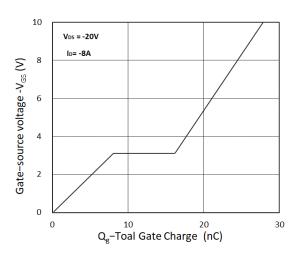


Figure 8. Gate Charge Characteristics

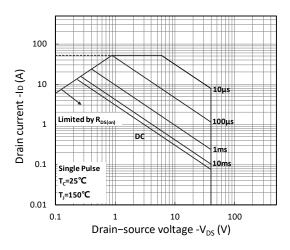


Figure 10. Safe Operating Area

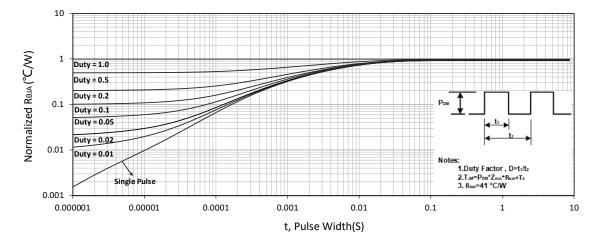
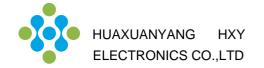


Figure 11. Normalized Maximum Transient Thermal Impedance



# **Test Circuit**

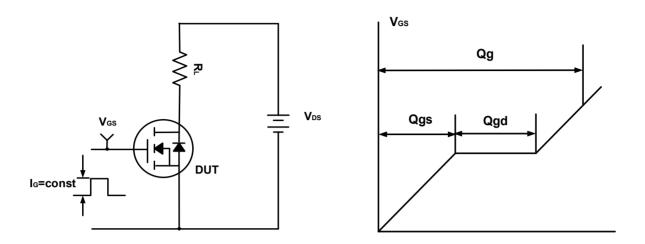


Figure A. Gate Charge Test Circuit & Waveforms

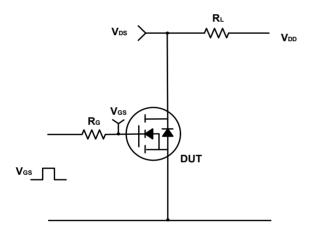


Figure B. Switching Test Circuit & Waveforms

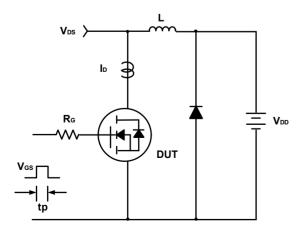
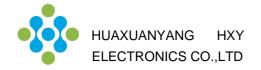
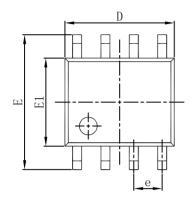
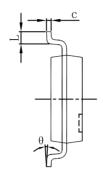


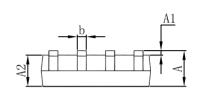
Figure C. Unclamped Inductive Switching Circuit & Waveforms



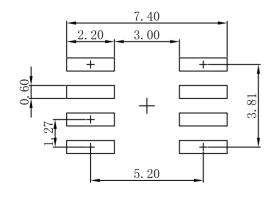
# **SOP-8(SOIC-8) Package Outline Dimensions**







Symbol	Dimensions In Millimeters		Dimensions In Inches		
	Min	Max	Min	Max	
A	1. 350	1.750	0.053	0.069	
A1	0.100	0. 250	0.004	0.010	
A2	1.350	1.550	0.053	0.061	
b	0.330	0.510	0.013	0.020	
c	0.170	0.250	0.007	0.010	
D	4.800	5.000	0.189	0. 197	
e	1.270 (BSC)		0.050 (BSC)		
E	5.800	6.200	0.228	0. 244	
E1	3.800	4.000	0.150	0. 157	
L	0.400	1.270	0.016	0.050	
θ	0°	8°	0°	8°	



- Note: 1.Controlling dimension:in millimeters.
- 2.General tolerance:± 0.05mm.
  3.The pad layout is for reference purposes only.

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